

## SCHOTTKY BARRIER RECTIFIER

VOLTAGE RANGE: 90 V  
CURRENT: 3.5 A

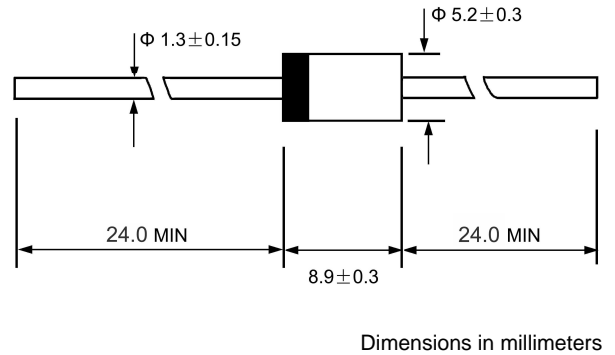
### FEATURES

- ◇ Metal-Semiconductor junction with guard ring
- ◇ Epitaxial construction
- ◇ Low forward voltage drop, low switching losses
- ◇ High surge capability
- ◇ For use in low voltage, high frequency inverters free wheeling, and polarity protection applications
- ◇ The plastic material carries U/L recognition 94V-0

### MECHANICAL DATA

- ◇ Case: JEDEC DO--27, molded plastic
- ◇ Terminals: Axial lead, solderable per MIL-STD-202, Method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.041 unces, 1.15 grams
- ◇ Mounting position: Any

### DO - 27



### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

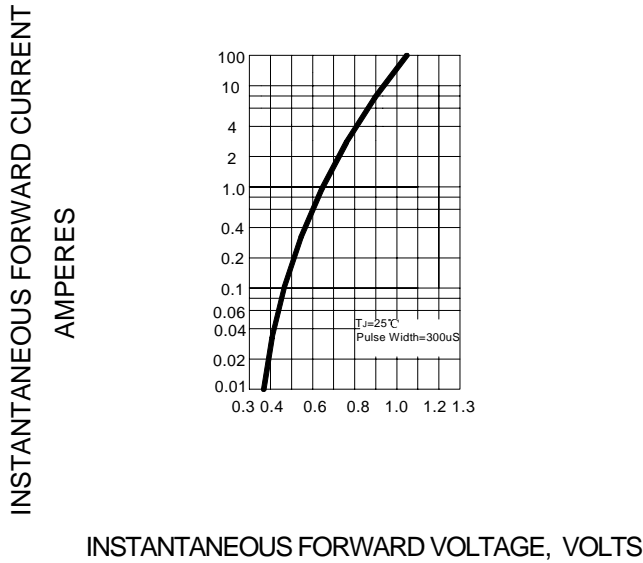
Single phase, half wave, 50 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		RK-49	UNITS
Maximum recurrent peak reverse voltage	$V_{RRM}$	90	V
Maximum RMS voltage	$V_{RMS}$	63	V
Maximum DC blocking voltage	$V_{DC}$	90	V
Maximum average forward rectified current 9.5mm lead length, @ $T_A=65^\circ\text{C}$	$I_{F(AV)}$	3.5	A
Peak forward surge current 10ms single half-sine-wave superimposed on rated load	$I_{FSM}$	60	A
Maximum instantaneous forward voltage ( $I_F=3.5A$ ) (Note1)	$V_F$	0.81	V
Maximum reverse current @ $T_A=25^\circ\text{C}$ at rated DC blocking voltage @ $T_A=100^\circ\text{C}$	$I_R$	5.0 35	mA
Typical thermal resistance (Note2)	$R_{\theta JL}$	8.0	$^\circ\text{C}/\text{W}$
Operating junction temperature range	$T_J$	- 55 ---- + 150	$^\circ\text{C}$
Storage temperature range	$T_{STG}$	- 55 ---- + 150	$^\circ\text{C}$

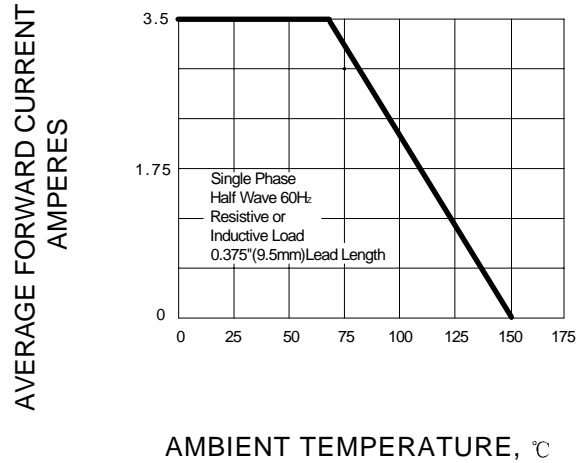
Note: 1. Pulse test : 300  $\mu$  s pulse width, 2% duty cycle.  
2. Thermal resistance junction to lead.

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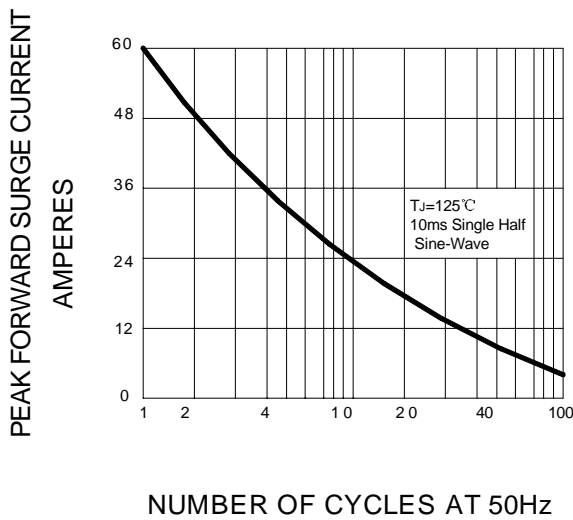
**FIG.1 – TYPICAL FORWARD CHARACTERISTIC**



**FIG.2- FORWARD DERATING CURVE**



**FIG.3- PEAK FORWARD SURGE CURRENT**



**FIG.4 – TYPICAL REVERSE CHARACTERISTICS**

